



A6A:50.XX

VOLTAGE RATINGS

Part Number	V_{RRM}, V_R (V) Max. rep. peak reverse voltage		V_{RSM}, V_R (V) Max. non- rep. peak reverse voltage
	$T_J = 0$ to 150°C	$T_J = -40$ to 0°C	$T_J = 25$ to 150°C
A6A:50.01	100	100	200
A6A:50.02	200	200	300
A6A:50.04	400	400	500
A6A:50.06	600	600	700
A6A:50.08	800	800	900

This datasheet applies to:

A6A:50.XX, A6B:50.XX

**For long lead, add "L"
to the end of part number**

MAXIMUM ALLOWABLE RATINGS

PARAMETER	VALUE	UNITS	NOTES
T_J Junction Temperature	-40 to 150	$^\circ\text{C}$	-
T_{stg} Storage Temperature	-40 to 150	$^\circ\text{C}$	-
$I_{F(AV)}$ Max. Av. current @ Max. T_C	50	A	180° half sine wave
	150	$^\circ\text{C}$	
$I_{F(RMS)}$ Nom. RMS current	78	A	-
I_{FSM} Max. Peak non-rep. surge current	634	A	50 Hz half cycle sine wave Initial $T_J = 150^\circ\text{C}$, rated V_{RRM} applied after surge.
	691		60 Hz half cycle sine wave
	700		50 Hz half cycle sine wave Initial $T_J = 150^\circ\text{C}$, no voltage applied after surge.
	830		60 Hz half cycle sine wave
I^2t Max. I^2t capability	1606	A^2s	$t = 10\text{ms}$ Initial $T_J = 150^\circ\text{C}$, rated V_{RRM} applied after surge.
	1751		$t = 8.3\text{ms}$
	2900		$t = 10\text{ms}$ Initial $T_J = 150^\circ\text{C}$, no voltage applied after surge.
	2490		$t = 8.3\text{ms}$
$I^2t^{1/2}$ Max. $I^2t^{1/2}$ capability	20	$\text{A}^2\text{s}^{1/2}$	Initial $T_J = 150^\circ\text{C}$, no voltage applied after surge. I^2t for time $t_x = I^2t^{1/2} * t_x^{1/2}$. ($0.1 < t_x < 10\text{ms}$).



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CHARACTERISTICS

PARAMETER	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
V _{FM} Peak forward voltage	---	---	1.30	V	Initial T _J = 25°C, sinusoidal wave, I _{peak} = 157A.
V _{F(TO)1} Low-level threshold	---	---	0.71	V	T _J = 180°C Av. power = V _{F(TO)} * I _{F(AV)} + r _F * [I _{F(RMS)}] ²
V _{F(TO)2} High-level threshold	---	---	0.93		
r _{F1} Low-level resistance	---	---	7.20	m	Use low values for I _{FM} < I _{F(AV)}
r _{F2} High-level resistance	---	---	3.60		
I _{RM} Peak reverse current	---	---	6.00	mA	T _J = 180°C. Max. Rated V _{RRM}
R _{thJC} Thermal resistance, junction-to-case	---	---	0.85	°C/W	DC operation
R _{thCS} Thermal resistance, case-to-sink	---	---	0.55	°C/W	Mtg. Surface smooth, flat and greased. Single side.
wt Weight	---	10(0.36)	---	g(oz.)	---
Case Style	Press-fit			---	---

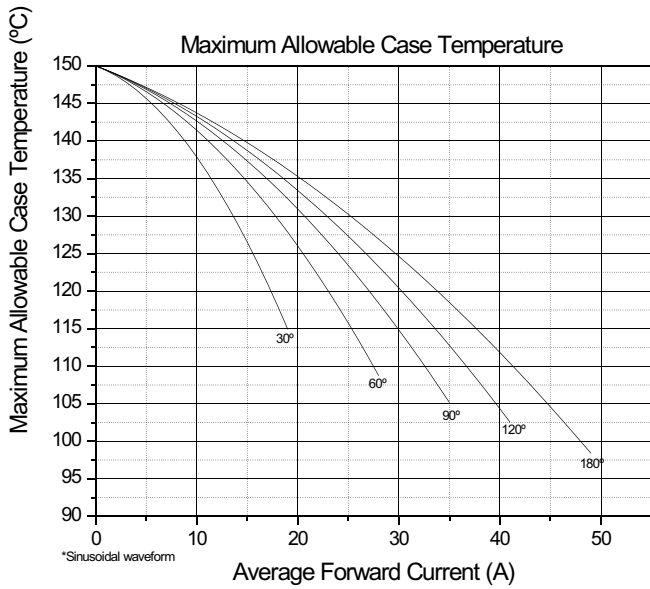


Fig. 1 - Current Ratings Characteristics

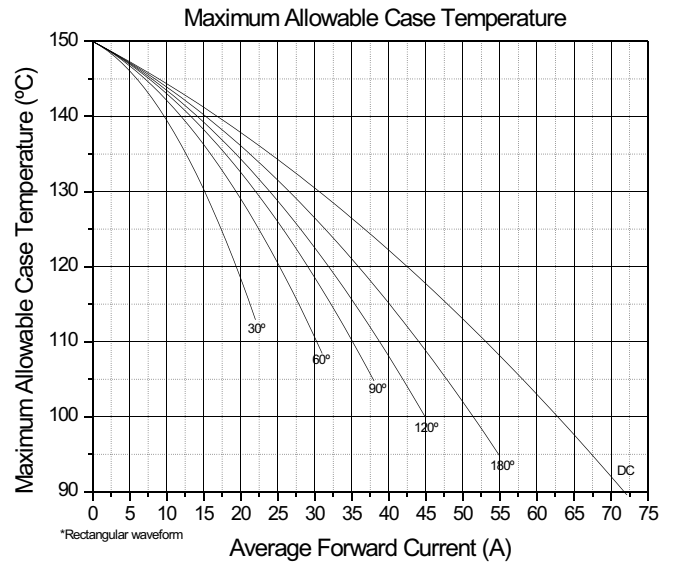


Fig. 2 - Current Ratings Characteristics



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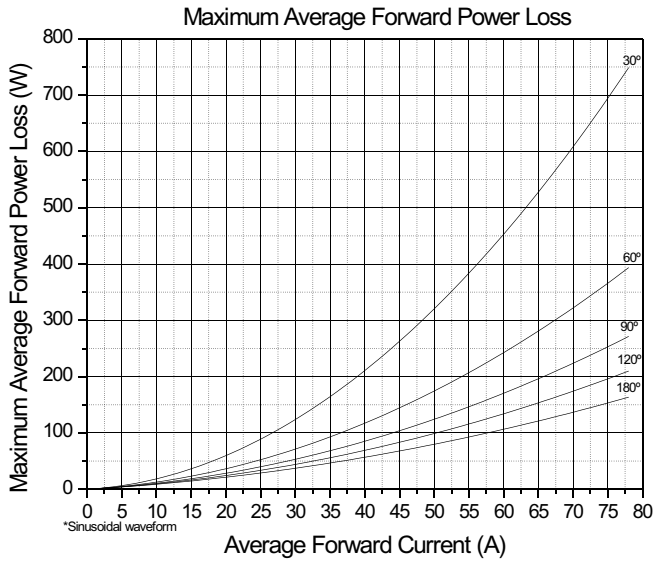


Fig. 3 - Average Forward Power Loss Characteristics

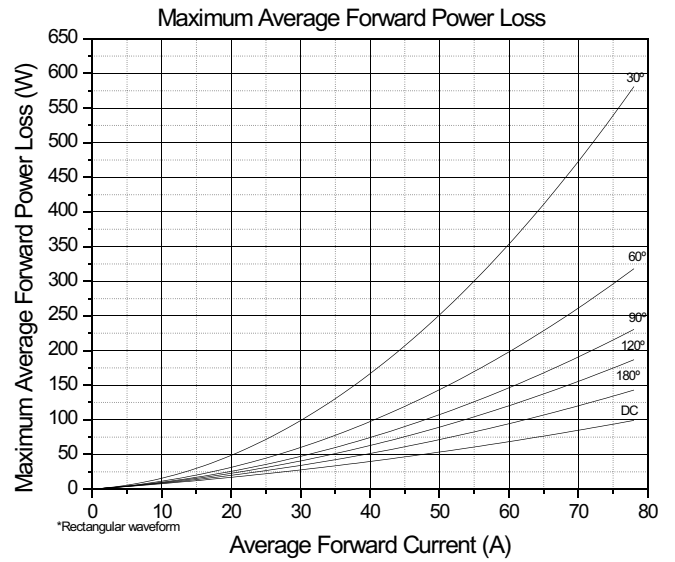


Fig. 4 - Average Forward Power Loss Characteristics

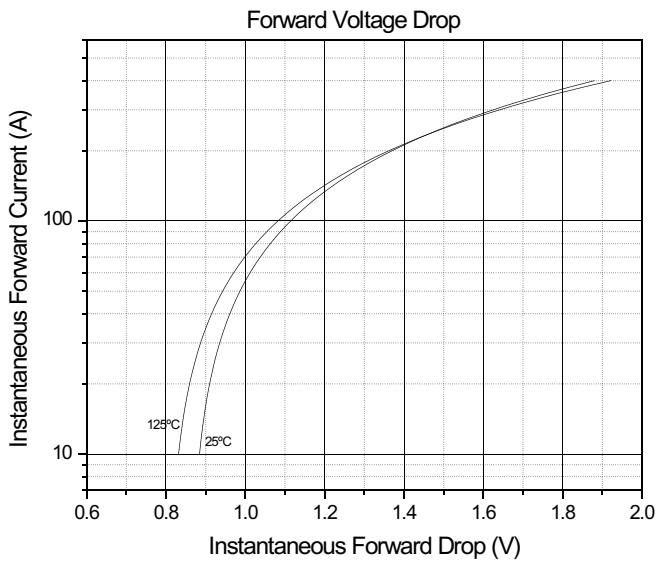


Fig. 5 - Forward Voltage Drop Characteristics

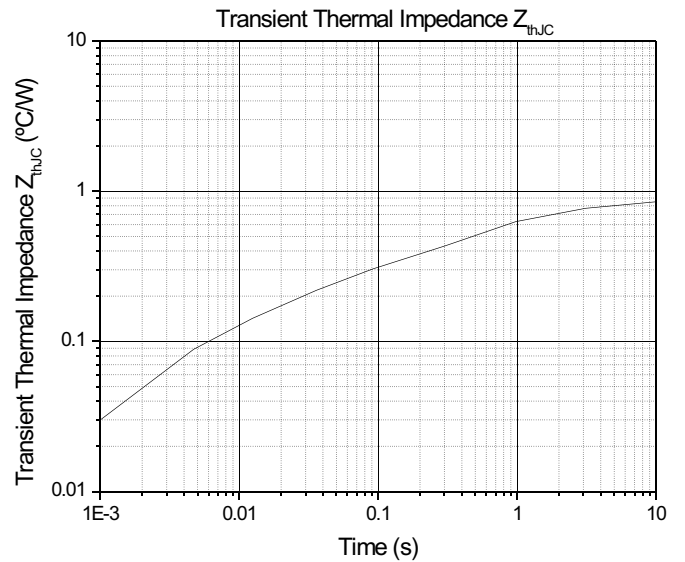


Fig. 6 - Transient Thermal Impedance Z_{thJC} Characteristics



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“Press-Fit”

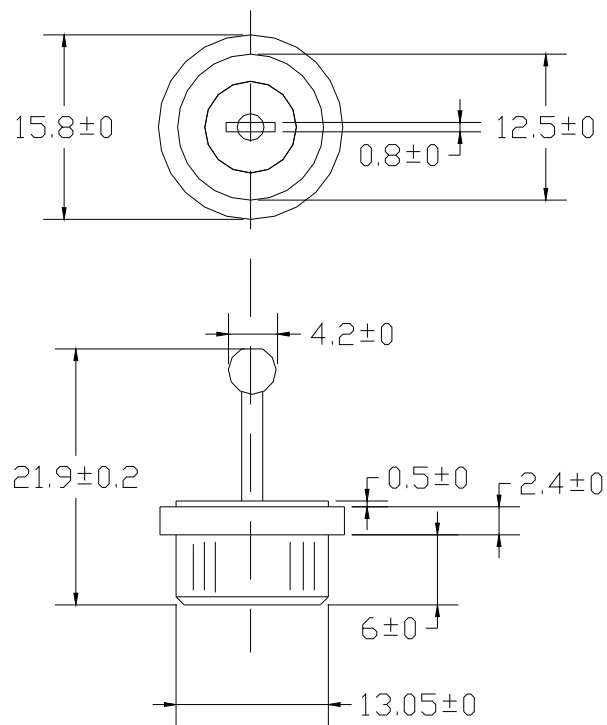


Fig. 7 - Outline Characteristics